

April 1988 Revised August 1999

74F620 • 74F623 Inverting Octal Bus Transceiver with 3-STATE Outputs

General Description

These devices are octal bus transceivers designed for asynchronous two-way data flow between the A and B busses. Both busses are capable of sinking $64\ mA$ and have 3-STATE outputs. Dual enable pins (GAB, $\overline{G}BA)$ allow data transmission from the A bus to the B bus or from the B bus to the A bus. The 74F620 is an inverting option of the 74F623.

Features

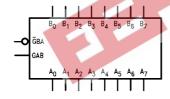
- Designed for asynchronous two-way data flow between busses
- Outputs sink 64 mA
- Dual enable inputs control direction of data flow
- Guaranteed 4000V minimum ESD protection
- 74F620 is an inverting option of the 74F623

Ordering Code:

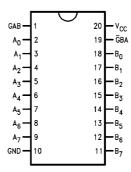
	Order Number	Package Number	Package Description		
74F620PC N20A 20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide					
	74F623SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide		
	74F623PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide		

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



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Unit Loading/Fan Out

Pin Names	Description	U.L.	Input I _{IH} /I _{IL}	
Pili Names	Description	HIGH/LOW	Output I _{OH} /I _{OL}	
GBA, GAB	Enable Inputs	1.0/1.0	20 μA/-0.6 mA	
A ₀ -A ₇	A Inputs or	3.5/1.083	70 μA/–0.4 mA	
	3-STATE Outputs	150/40	−3 mA/64 mA	
B ₀ –B ₇	B Inputs or	3.5/1.083	70 μA/–0.4 mA	
	3-STATE Outputs	150/40	−3 mA/64 mA	

Functional Description

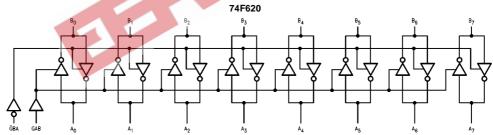
The enable inputs GAB and $\overline{\text{G}}\text{BA}$ control whether data is transmitted from the A bus to the B bus or from the B bus to the A bus. If both GBA and GAB are disabled (GBA HIGH and GAB LOW), the outputs are in the high impedance state and data is stored at the A and B busses. When GBA is active LOW, B data is sent to the A bus. When GAB is active HIGH, data from the A bus is sent to the B bus. If both enable inputs are active (GBA LOW and GAB HIGH) B data is sent to the A bus while A data is sent to the B bus.

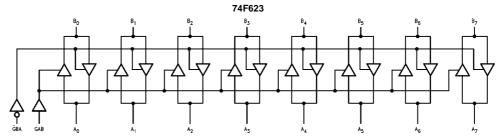
Function Table

		O					
Enable	Inputs	Operation					
GBA GAB		74F620	74F623				
L	L	B Data to A Bus	B Data to A Bus				
Н	Н	A Data to B Bus	A Data to B Bus				
Н	L.L.	Z	Z				
н.	Н	B Data to A Bus,	B Data to A Bus,				
	-	A Data to B Bus	A Data to B Bus				

- H = HIGH Voltage Level L = LOW Voltage Level Z = High Impedance

Logic Diagrams





Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

-65°C to +150°C

 $\begin{array}{lll} \mbox{Ambient Temperature under Bias} & -55^{\circ}\mbox{C to } +125^{\circ}\mbox{C} \\ \mbox{Junction Temperature under Bias} & -55^{\circ}\mbox{C to } +150^{\circ}\mbox{C} \\ \mbox{V}_{\mbox{CC}} \mbox{ Pin Potential to Ground Pin} & -0.5\mbox{V to } +7.0\mbox{V} \\ \end{array}$

Input Voltage (Note 2) -0.5 V to +7.0 V Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Output

Storage Temperature

in HIGH State (with $V_{CC} = 0V$)

Standard Output -0.5V to V_{CC} 3-STATE Output -0.5V to +5.5V

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA) ESD Last Passing Voltage (Min) 4000V

Recommended Operating Conditions

Free Air Ambient Temperature $0^{\circ}\text{C} \text{ to } +70^{\circ}\text{C}$ Supply Voltage +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

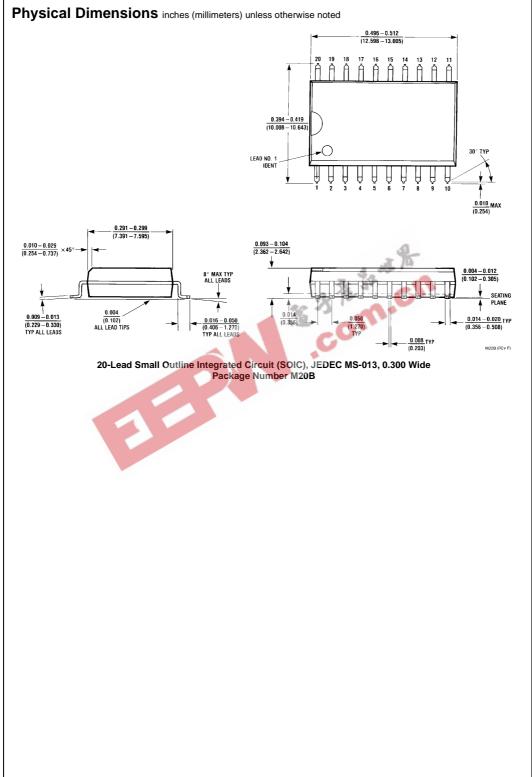
Note 2: Either voltage limit or current limit is sufficient to protect inputs.

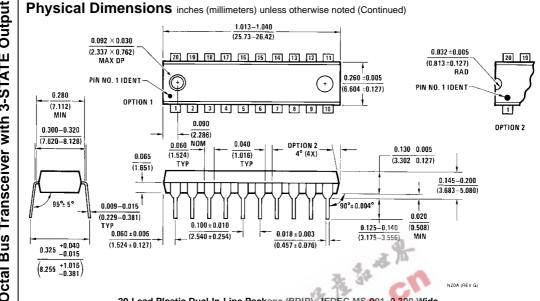
DC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Units	V _{cc}	Conditions
V _{IH}	Input HIGH Voltage	2.0			V	4	Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA (Non I/O Pins)
V _{OH}	Output HIGH 10% V _{CC}	2.0		CAL	V	Min	$I_{OH} = -15 \text{ mA } (A_n, B_n)$
V _{OL}	Output LOW 10% V _{CC}	1		0.55	V	Min	I _{OL} = 64 mA (A _n , B _n)
I _{IH}	Input HIGH Current			5.0	μА	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test			7.0	μΑ	Max	V _{IN} = 7.0V (GBA, GAB)
I _{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	$V_{IN} = 5.5V (A_n, B_n)$
I _{CEX}	Output HIGH Leakage Current			50	μΑ	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test	4.75			V	0.0	$I_{ID} = 1.9 \mu\text{A}$ All Other Pins Grounded
I _{OD}	Output Leakage Circuit Current			3.75	μА	0.0	V _{IOD} = 150 mV All Other Pins Grounded
I _{IL}	Input LOW Current			-0.6	mA	Max	V _{IN} = 0.5V (Non I/O Pins)
I _{IH} + I _{OZH}	Output Leakage Current			70	μА	Max	$V_{OUT} = 2.7V (A_n, B_n)$
$I_{IL} + I_{OZL}$	Output Leakage Current			-650	μА	Max	$V_{OUT} = 0.5V (A_n, B_n)$
Ios	Output Short-Circuit Current	-100		-225	mA	Max	V _{OUT} = 0V
I _{ZZ}	Bus Drainage Test			500	μА	0.0V	V _{OUT} = 5.25V
I _{CCH}	Power Supply Current (74F620)			82	mA	Max	$V_0 = HIGH, V_{IN} = 0.2V$
I _{CCL}	Power Supply Current (74F620)			82	mA	Max	$V_O = LOW$
I _{CCZ}	Power Supply Current (74F620)			95	mA	Max	$V_0 = HIGH Z$
I _{CCH}	Power Supply Current (74F623)			65	mA	Max	V _O = HIGH
I _{CCL}	Power Supply Current (74F623)			82	mA	Max	$V_O = LOW, V_{IN} = 0.2V$
I _{CCZ}	Power Supply Current (74F623)			85	mA	Max	$V_O = HIGH Z$

AC Electrical Characteristics

	Parameter	$T_A = +25$ °C $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$			$T_A = 0$ °C to +70°C $V_{CC} = +5.0$ V $C_L = 50$ pF		Units
Symbol							
		Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay	2.5		7.5	2.0	8.0	ns
t _{PHL}	A Input to B Output (74F620)	2.0		7.0	2.0	7.0	115
t _{PLH}	Propagation Delay	2.5		7.5	2.0	8.0	
t _{PHL}	B Input to A Output (74F620)	2.0		7.0	2.0	7.0	ns
t _{PLH}	Propagation Delay	1.5		6.5	1.5	7.5	
t _{PHL}	A Input to B Output (74F623)	2.0		7.0	2.0	7.5	ns
t _{PLH}	Propagation Delay	1.5		6.5	1.5	7.5	
t _{PHL}	B Input to A Output (74F623)	2.0		7.0	2.0	7.5	ns
t _{PZH}	Enable Time	2.0		7.0	2.0	8.0	
t_{PZL}	GBA Input to A Output	2.5		8.0	2.0	8.5	
t _{PHZ}	Disable Time	1.5		6.5	1.5	7.5	ns
t _{PLZ}	GBA Input to A Output	1.0		5.5	1.0	5.5	
t _{PZH}	Enable Time	2.0		7.5	2.0	8.5	
t _{PZL}	GAB Input to B Output (74F620)	3.0		8.0	2.0	8.5	
t _{PHZ}	Disable Time	2.5	25.0	8.0	2.0	9.0	ns
t_{PLZ}	GAB Input to B Output (74F620)	2.0	12 19	7.5	2.0	8.0	
t _{PZH}	Enable Time	2.0	73	7.5	2.0	8.5	
t_{PZL}	GAB Input to B Output (74F623)	2.5		8.0	2.0	8.5	
t _{PHZ}	Disable Time	2.0	~0	8.0	2.0	9.0	ns
t_{PLZ}	GAB Input to B Output (74F623)	2.0	C	8.0	2.0	8.0	
			C				





20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide Package Number N20A

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